IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

    Naoshi ADACHI

Serial No.:   to be assigned

Filed: January 5, 2004

For: HEAT TREATMENT JIG FOR SEMICONDUCTOR SUBSTRATE AND METHOD OF HEAT TREATING SEMICONDUCTOR FOR SUBSTRATE

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents
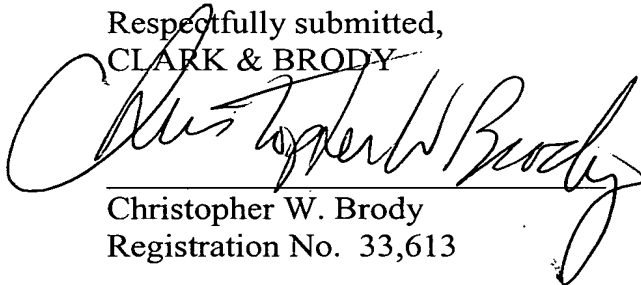P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

In accordance with the provisions of 37 C.F.R. 1.56, 1.97 and 1.98, the attention of the Patent and Trademark Office is hereby directed to the references listed on the attached form PTO-1449. It is respectfully requested that the references be expressly considered during the prosecution of this application, and that the references be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

Applicants respectfully submit that this disclosure is being made with the filing of the application, hence, no fee is required.

Respectfully submitted,
CLARK & BRODY

Christopher W. Brody
Registration No. 33,613

Customer No. 22902
1750 K Street NW, Suite 600
Washington DC 20006
Telephone: 202-835-1111
Facsimile: 202-835-1755

Docket No.: 12054-0023
Date: January 5, 2004

FORM PTO-1449 INFORMATION DISCLOSURE CITATION	Attorney Docket: 12054-0023	Serial No.: to be assigned
	Applicant: Naohsi ADACHI et al.	
	Filing Date: January 5, 2004	Group:

U.S. PATENT DOCUMENTS

Examiner Initial		Document Number	Date	Name	Class	Sub-Class	Filing Date

FOREIGN PATENT DOCUMENTS

Examiner Initial		Document Number	Date	Country	Class	Sub-Class	Translation Yes	No
		2001-358086	12/26/2001	Japan			x	
		2003-037112	02/07/2003	Japan			x	
		09-199438	07/31/1997	Japan			x	
		10-270369	10/09/1998	Japan			x	

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)

Examiner:	Date Considered:

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.